

MICRO POWER SYSTEMS INC

T-51-11

# MP7510DI, MP7511DI, MP7512DI

**CMOS QUAD SPST ANALOG SWITCHES (MP7510DI, MP7511DI)**

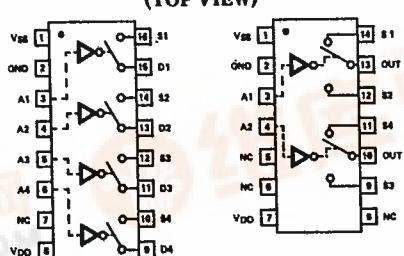
**CMOS DUAL SPDT ANALOG SWITCH (MP7512DI)**

## FEATURES

- Latch-Proof
- Overvoltage Protected
- Low  $R_{ON}$  : 75Ω
- Low Dissipation: 3 mW
- TTL/CMOS Direct Interface
- Silicon-Nitride Passivated
- Monolithic Dielectrically-Isolated CMOS

## PIN CONFIGURATIONS

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MP7510DI  
MP7511DI

MP7512DI

## GENERAL DESCRIPTION

The MP7510DI, MP7511DI and MP7512DI are a family of latch proof dielectrically isolated CMOS switches featuring overvoltage protection up to  $\pm 25V$  above the power supplies. These benefits are obtained without sacrificing the low "ON" resistance (75Ω) or low leakage current (400pA), the main features of an analog switch.

The MP7510DI and MP7511DI consist of four independent SPST analog switches packaged in a 16-pin DIP. They differ only in that the digital control logic is inverted. The MP7512DI has two independent SPDT switches packaged in a 14-pin DIP.

Very low power dissipation, overvoltage protection and TTL/CMOS direct interfacing are achieved by combining a unique circuit design and a dielectrically isolated CMOS process. Silicon nitride passivation ensures long term stability while monolithic construction provides reliability.

## CONTROL LOGIC

MP7510DI: Switch "ON" for Address "HIGH"

MP7511DI: Switch "ON" for Address "LOW"

MP7512DI: Address "HIGH" makes S1 to Out-1 and S3 to Out-2

See Section 7 for Ordering Information

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# MP7510DI, MP7511DI, MP7512DI

SPECIFICATIONS ( $V_{DD} = +15V$ ,  $V_{SS} = -15V$  unless otherwise noted)

COMMERCIAL VERSIONS (J, K)

PARAMETER <sup>4</sup>	MODEL	VERSION	25°C	0°C to 70°C (N) -25°C to +85°C (D)		UNITS	TEST CONDITIONS
				MIN	MAX		
<b>ANALOG SWITCH</b>							
$R_{ON}$ <sup>1</sup>	All	J, K	100 max		175	Ω	$-10V \leq V_D \leq +10V$ $I_{DS} = 1.0\text{ mA}$
$R_{ON}$ vs $V_D$ ( $V_S$ )	All	J, K	20 typ			%	
$R_{ON}$ Drift	All	J, K	+0.5 typ			%/°C	
$R_{ON}$ Match	All	J, K	1 typ			%	
$R_{ON}$ Drift Match	All	J, K	0.01 typ			%/°C	$V_D = 0$ , $I_{DS} = 1.0\text{ mA}$
$I_D$ ( $I_S$ )OFF <sup>1</sup>	All	J, K	5 max		500	nA	$V_D = -10V$ , $V_S = +10V$ and $V_D = +10V$ , $V_S = -10V$
$I_D$ ( $I_S$ )ON <sup>2</sup>	All	J, K	10 max			nA	$V_S = V_D = +10V$ $V_S = V_D = -10V$
$I_{OUT}$ <sup>1</sup>	MP7512DI	J, K	15 max		1500	nA	$V_{S1} = V_{OUT} = \pm 10V$ , $V_{S2} = \mp 10V$ and $V_{S2} = V_{OUT} = \pm 10V$ , $V_{S1} = \mp 10V$
<b>DIGITAL CONTROL</b>							
$V_{INL}$ <sup>1</sup>	All	J, K			0.8	V	
$V_{INH}$ <sup>1</sup>	All	K		2.4		V	
$C_{IN}$	All	J, K	3 typ			pF	
$I_{INH}$ <sup>1</sup>	All	J, K	10 max			nA	$V_{IN} = V_{DD}$
$I_{INL}$ <sup>1</sup>	All	J, K	10 max			nA	$V_{IN} = 0$
<b>DYNAMIC CHARACTERISTICS</b>							
$t_{ON}$	MP7510DI MP7511DI	J, K J, K	180 typ 350 typ			ns ns	
$t_{OFF}$	MP7510DI MP7511DI	J, K J, K	350 typ 180 typ			ns ns	$V_{IN} = 0$ to +3.0V
$t_{TRANSITION}$	MP7512DI	J, K	300 typ			ns	
$C_S$ (CD)OFF	All	J, K	8 typ			pF	
$C_S$ (CD)ON	All	J, K	17 typ			pF	
$C_{DS}$ (CS-OUT)	All	J, K	1 typ			pF	$V_D$ ( $V_S$ ) = 0V
$C_{DD}$ ( $C_{SS}$ )	All	J, K	0.5 typ			pF	
$C_{OUT}$	MP7512DI	J, K	17 typ			pF	
$Q_{INJ}$	All	J, K	30 typ			pC	Measured at S or D terminal. $C_L = 1000\text{ pF}$ , $V_{IN} = 0$ to 3V, $V_D$ ( $V_S$ ) = +10V to -10V
<b>POWER SUPPLY</b>							
$I_{DD}$ <sup>1</sup>	All	J, K	800 max		800	μA	All digital inputs = $V_{INH}$
$I_{SS}$ <sup>1</sup>	All	J, K	800 max		800	μA	
$I_{DD}$ <sup>1</sup>	All	J, K	500 max		500	μA	
$I_{SS}$ <sup>1</sup>	All	J, K	500 max		500	μA	All digital inputs = $V_{INL}$

## Notes

<sup>1</sup> 100% tested.<sup>2</sup> Guaranteed, not production tested.<sup>3</sup> A pullup resistor, typically 1-2 kΩ is required to make "J" versions TTL compatible.<sup>4</sup> Specifications subject to change without notice.

CAUTION: The digital control inputs are zener protected; however, permanent damage may occur on unconnected units under high electrostatic fields. Keep unused units in conductive foam at all times. Prior to pulling the devices from the conductive foam, ground the foam to deplete any accumulated charge.

MICRO<sup>1</sup> POWER SYSTEMS INC**MP7510DI, MP7511DI, MP7512DI****SPECIFICATIONS (V<sub>DD</sub> = ±15V, V<sub>SS</sub> = -15V unless otherwise noted)**

MILITARY VERSIONS (S, T)

PARAMETER <sup>4</sup>	MODEL	VERSION	25°C MAX	-55°C to +125°C		UNITS	TEST CONDITIONS
				MIN	MAX		
<b>ANALOG SWITCH</b>							
R <sub>ON</sub> <sup>1</sup>	All	S, T	100		175	Ω	-10V ≤ V <sub>D</sub> ≤ +10V I <sub>DS</sub> = 1 mA
I <sub>D</sub> (I <sub>S</sub> )OFF <sup>1</sup>	All	S, T	3		200	nA	V <sub>D</sub> = -10V, V <sub>S</sub> = +10V and V <sub>D</sub> = +10V, V <sub>S</sub> = -10V
I <sub>D</sub> (I <sub>S</sub> )ON <sup>2</sup>	All	S, T	10		600	nA	V <sub>S</sub> = V <sub>D</sub> = +10V and V <sub>S</sub> = V <sub>D</sub> = -10V
I <sub>QUT</sub> <sup>1</sup>	MP7512DI	S, T	9		600	nA	V <sub>S1</sub> = V <sub>OUT</sub> = ±10V V <sub>S2</sub> = ±10V and V <sub>S2</sub> = V <sub>OUT</sub> = ±10V V <sub>S1</sub> = ±10V
<b>DIGITAL CONTROL</b>							
V <sub>INL</sub> <sup>1</sup>	All	S, T			0.8	V	
V <sub>INH</sub> <sup>1,3</sup>	MP7510DI	S		2.4		V	
	MP7511DI	T		2.4		V	
	MP7512DI	S		3.0		V	
	MP7511DI MP7512DI						
I <sub>INH</sub> <sup>1</sup>	All	S, T	10			nA	V <sub>IN</sub> = V <sub>DD</sub>
I <sub>INL</sub> <sup>1</sup>	All	S, T	10			nA	V <sub>IN</sub> = 0
<b>DYNAMIC CHARACTERISTICS</b>							
t <sub>ON</sub> <sup>2</sup>	MP7510DI MP7511DI	S, T	1.0			μs	V <sub>IN</sub> = 0 to +3V
t <sub>OFF</sub> <sup>2</sup>	MP7510DI MP7511DI	S, T	1.0			μs	
t <sub>TRANSITION</sub> <sup>2</sup>	MP7512DI	S, T	1.0			μs	
<b>POWER SUPPLY</b>							
I <sub>DD</sub> <sup>1</sup>	All	S, T		800		μA	All digital inputs = V <sub>INH</sub>
I <sub>SS</sub> <sup>1</sup>	All	S, T		800		μA	
I <sub>DD</sub> <sup>1</sup>	All	S, T		500		μA	All digital inputs = V <sub>INL</sub>
I <sub>SS</sub> <sup>1</sup>	All	S, T		500		μA	

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**ABSOLUTE MAXIMUM RATINGS**

V <sub>DD</sub> to Gnd . . . . .	+17V
V <sub>SS</sub> to Gnd . . . . .	-17V
Overtoltage at V <sub>D</sub> (V <sub>S</sub> ) (1 second surge) . . . . .	V <sub>DD</sub> +25V or V <sub>SS</sub> -25V
(Continuous) . . . . .	V <sub>DD</sub> +20V or V <sub>SS</sub> -20V
Switch Current (I <sub>DS</sub> , Continuous) . . . . .	50 mA
Switch Current (I <sub>DS</sub> , Surge) 1 ms Duration, 10% Duty Cycle . . . . .	150 mA

Digital Input Voltage Range . . . . .	0V to V <sub>DD</sub>
Power Dissipation (Package) Up to +75°C . . . . .	450 mW
Derates above +75°C by . . . . .	6 mW/°C
Storage Temperature . . . . .	-65°C to +150°C
Operating Temperature Plastic (J, K Versions) . . . . .	0°C to +70°C
Ceramic (J, K Versions) . . . . .	-25°C to +85°C
Ceramic (S, T Versions) . . . . .	-55°C to +125°C

**Notes**<sup>1</sup> 100% tested.<sup>2</sup> Guaranteed, not production tested.<sup>3</sup> A pullup resistor, typically 1-2 kΩ is required to make the MP7511DISD and MP7512DISD TTL compatible.<sup>4</sup> Specifications subject to change without notice.